

240V P-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET
Features

- $BV_{DSS} > -240V$
- $R_{DS(on)} \leq 8.8\Omega$ @ $V_{GS} = -3.5V$
- Low threshold and Fast switching
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

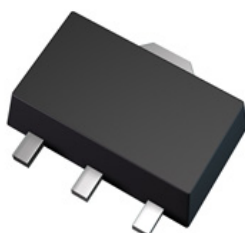
Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish ^(e3)
- Weight: 0.052 grams (approximate)

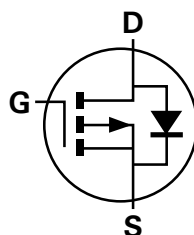
Application

- Electronic hook switches
- Telecoms and Battery powered equipment

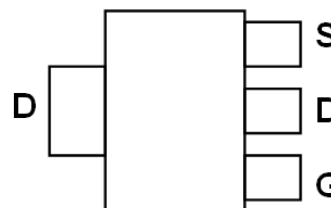
SOT89



Top View



Device symbol

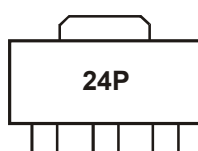


Pin-out Top

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVP4424ZTA	AEC-Q101	24P	7	12	1,000
ZVP4424ZQTA	Automotive	24P	7	12	1,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
 5. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information


24P = Product type Marking Code

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

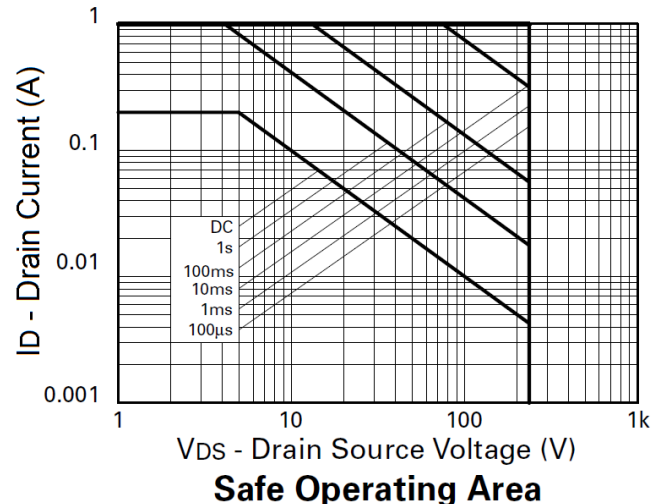
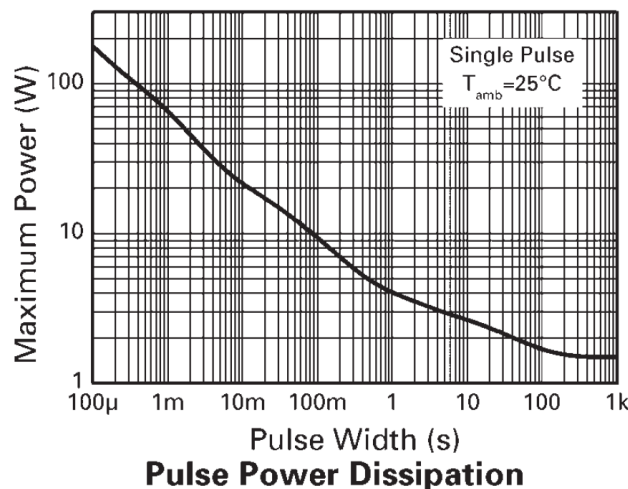
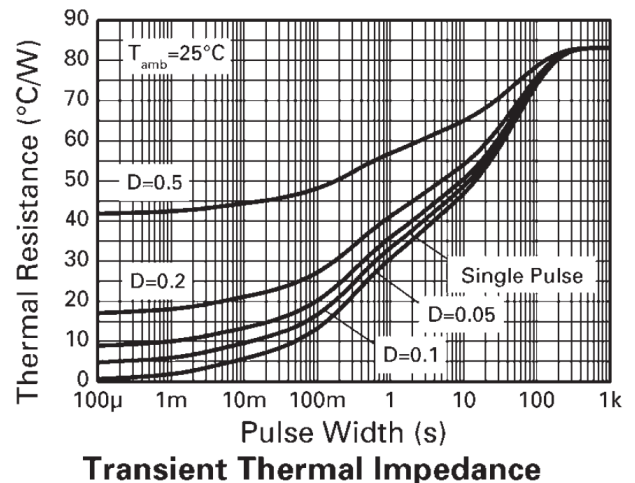
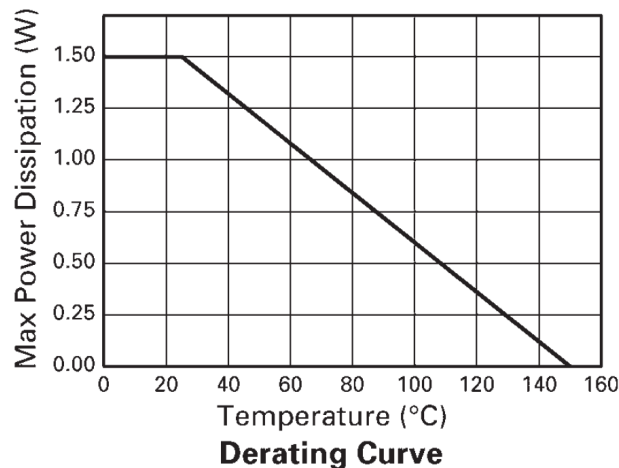
Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	-240	V
Gate-Source Voltage	V_{GSS}	± 40	V
Continuous Drain Current	I_D	-200	mA
Pulsed Drain Current (Note 8)	I_{DM}	-1.0	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P_D	1.5	W
		2.6	W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	83.3	$^\circ\text{C/W}$
		47.4	$^\circ\text{C/W}$
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	3.64	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
6. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
 7. For a device surface mounted on FR4 PCB measured at $t \leq 10$ sec.
 8. Repetitive rating - 25mm x 25mm FR4 PCB, $D = 0.02$, pulse width 300 μs - pulse width limited by maximum junction temperature.
 9. Thermal resistance from junction to solder-point (at the end of the drain lead).

Thermal Characteristics

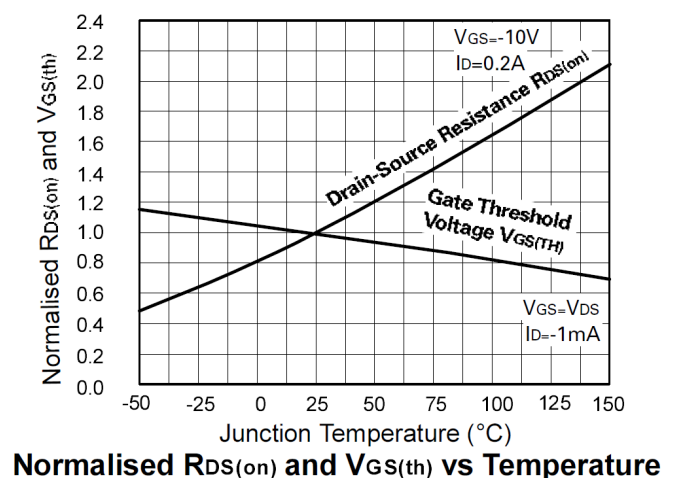
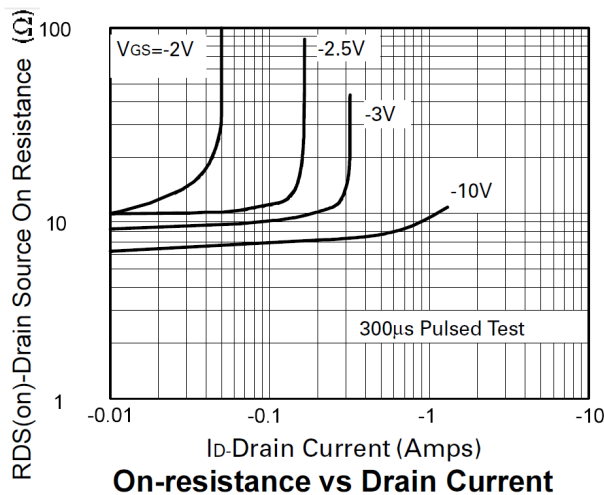
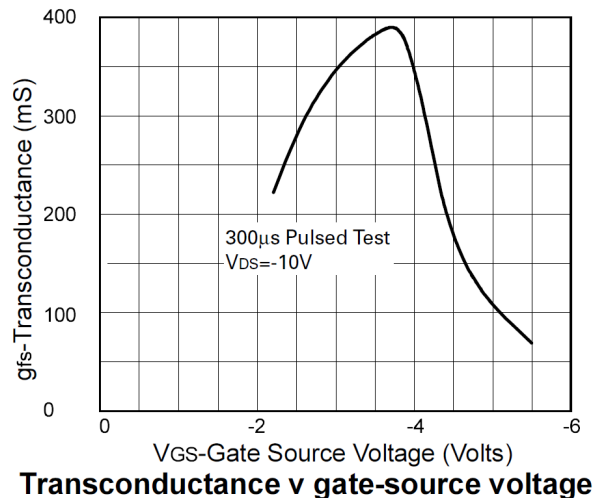
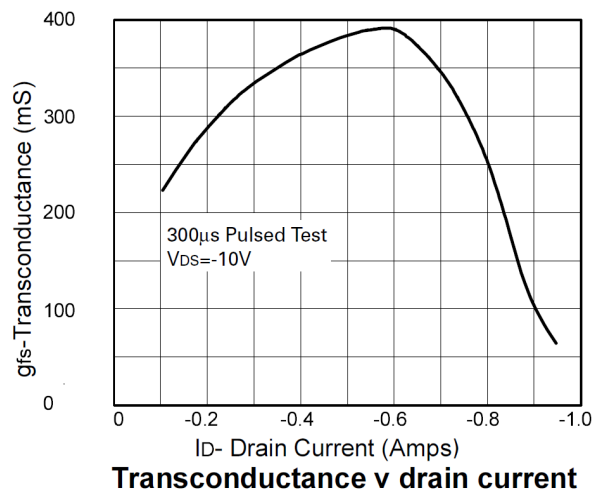
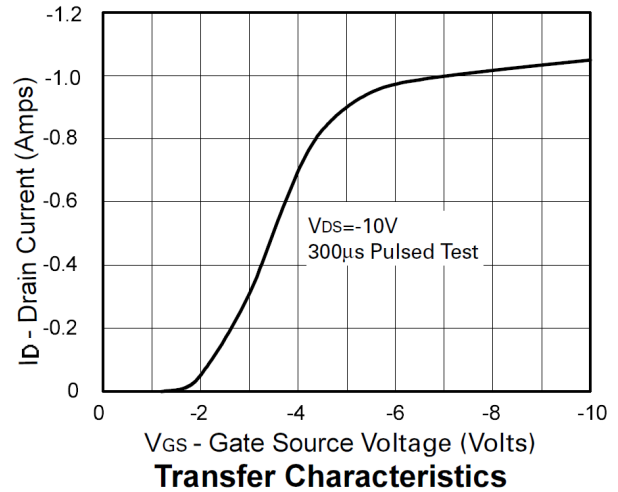
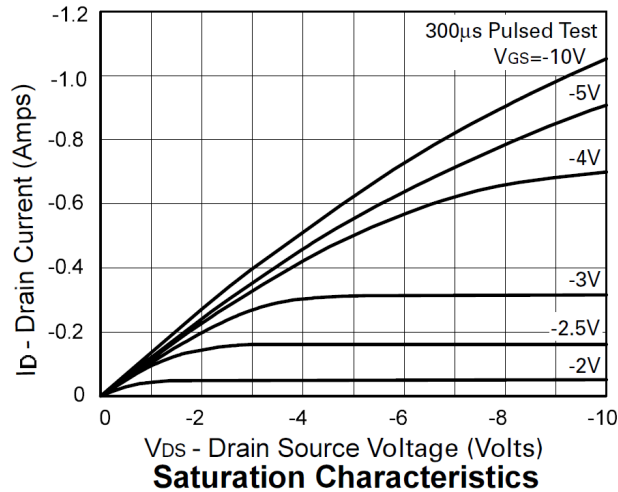


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	-240	—	—	V	I _D = -1mA, V _{GS} = 0V
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-10 -100	μA μA	V _{DS} = -240V, V _{GS} = 0V V _{DS} = -190V, V _{GS} = 0V, T _A = +125°C
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±40V, V _{DS} = 0V
ON CHARACTERISTICS						
On state Drain Current (Note 10)	I _{D(on)}	-0.75	-1.0	—	A	V _{DS} = -10V, V _{GS} = -10V
Gate Threshold Voltage	V _{GS(th)}	-0.7	-1.4	-2.0	V	I _D = -1mA, V _{DS} = V _{GS}
Static Drain-Source On-Resistance (Note 10)	R _{DS(on)}	—	7.1 8.8	9 11	Ω	V _{GS} = -10V, I _D = -200mA V _{GS} = -3.5V, I _D = -100mA
Forward Transconductance (Notes 10 & 12)	g _{fs}	125	—	—	mS	V _{DS} = -10V, I _D = -200mA
DYNAMIC CHARACTERISTICS (Note 12)						
Input Capacitance	C _{iss}	—	100	200	pF	V _{DS} = -25V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}	—	18	25		
Reverse Transfer Capacitance	C _{rss}	—	5	15		
Turn-On Delay Time (Note 11)	t _{d(on)}	—	8	15	ns	V _{DD} = -50V, I _D = -250mA V _{GEN} = -10V
Rise Time (Note 11)	t _r	—	8	15		
Turn-Off Delay Time (Note 11)	t _{d(off)}	—	26	40		
Fall Time (Note 11)	t _f	—	20	30		

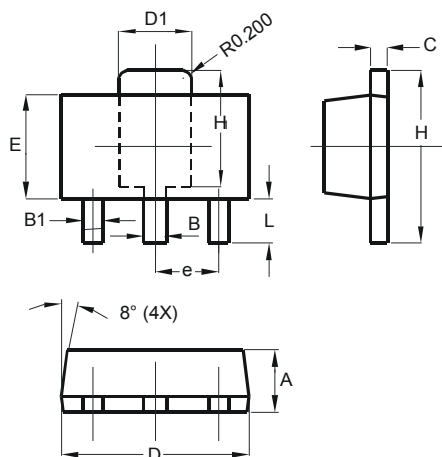
Notes: 10. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤ 2%.
11. Switching characteristics are independent of operating junction temperature.
12. For design aid only, not subject to production testing.

Typical Characteristics



Package Outline Dimensions

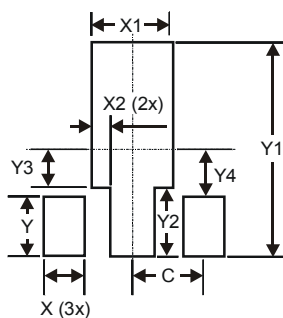
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT89		
Dim	Min	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.44
D	4.40	4.60
D1	1.62	1.83
E	2.29	2.60
e	1.50 Typ	
H	3.94	4.25
H1	2.63	2.93
L	0.89	1.20
All Dimensions in mm		

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500

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